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BLF7G24L-100; BLF7G24LS-100 Power LDMOS transistor Rev. 5 — 1 September 2015

AMPLEON

Product data sheet

Product profile

1.1 General description

100 W LDMOS power transistor for base station applications at frequencies from 2300 MHz to 2400 MHz.

Typical performance Table 1.

Typical RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Mode of operation	f	I_{Dq}	V _{DS}	$P_{L(AV)}$	Gp	η_D	ACPR _{885k}	ACPR _{5M}
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)
IS-95	2300 to 2400	900	28	20	18	27	-46 ^[1]	-
1 carrier W-CDMA	2300 to 2400	900	28	30	18.7	33	-	-40 ^[2]

^[1] Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 2300 MHz to 2400 MHz frequency range

^{[2] 3}GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.

2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
BLF7G24	L-100 (SOT502A)			
1	drain			,
2	gate		$\begin{array}{cccccccccccccccccccccccccccccccccccc$	نے
3	source	<u>[1]</u>		2 - +
				3 sym112
BLF7G24	LS-100 (SOT502B)			<u> </u>
1	drain			_
2	gate		3	نہ
3	source	<u>[1]</u>	2	2
				3 sym112
				3y11112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package							
	Name	Description	Version					
BLF7G24L-100	-	flanged LDMOST ceramic package; 2 mounting holes; 2 leads	SOT502A					
BLF7G24LS-100	-	earless flanged LDMOST ceramic package; 2 leads	SOT502B					

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	М	in	Max	Unit
V_{DS}	drain-source voltage		-		65	V
V_{GS}	gate-source voltage		-(0.5	+13	V
I _D	drain current		-		28	Α
T _{stg}	storage temperature		-6	35	+150	°C
Tj	junction temperature		-		200	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T_{case} = 80 °C; P_{L} = 100 W	0.3	K/W

BLF7G24L-100_7G24LS-100#5

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6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V_{GS} = 0 V; I_D = 1 mA	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 150 mA	1.5	1.8	2.3	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	5	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	25.1	29	-	Α
I _{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	500	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 5.35 A	-	10.5	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 5.25 \text{ A}$	-	0.1	-	Ω

7. Test information

Remark: All testing performed in a class-AB production test circuit.

Table 7. Functional test information

Mode of operation: 1-carrier N-CDMA, single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF, channel bandwidth is 1.2288 MHz; f_1 = 2300 MHz; f_2 = 2400 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 900 mA; T_{Case} = 25 °C; unless otherwise specified.

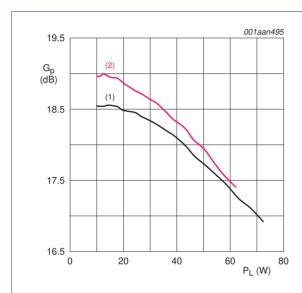
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_{L(AV)}$	average output power		-	20	-	W
Gp	power gain		17.3	18	-	dB
RLin	input return loss		-	-14	-	dB
η_{D}	drain efficiency		22	27	-	%
ACPR _{885k}	adjacent channel power ratio (885 kHz)		-	-46	-40	dBc

7.1 Ruggedness in class-AB operation

The BLF7G24L-100 and BLF7G24LS-100 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{Dq} = 900 \text{ mA}$; $P_L = 100 \text{ W}$ (CW); f = 2300 MHz.

7.2 Single carrier IS-95

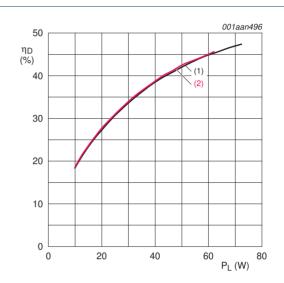
Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = $9.7 \, dB$ at $0.01 \, \%$ probability on the CCDF. Channel bandwidth is $1.2288 \, MHz$.



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2400 MHz

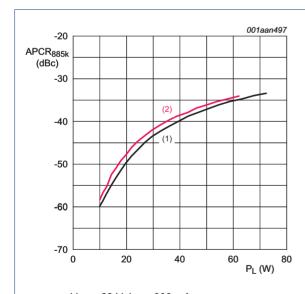
Fig 1. Single carrier IS-95 power gain as a function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2400 MHz

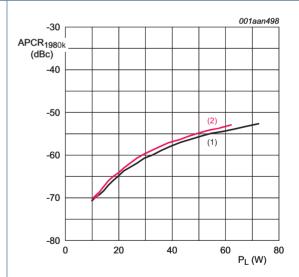
Fig 2. Single carrier IS-95 drain efficiency as a function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 900 mA.

- (1) f = 2300 MHz
- (2) f = 2400 MHz

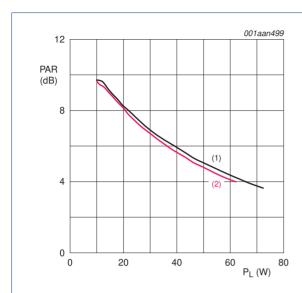
Fig 3. Single carrier IS-95 ACPR at 885 kHz as a function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2400 MHz

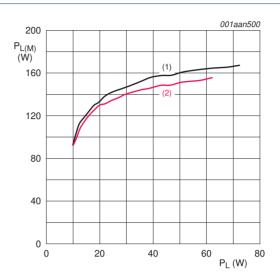
Fig 4. Single carrier IS-95 ACPR at 1980 kHz as a function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 5. Single carrier IS-95 peak-to-average power ratio as a function of load power; typical values

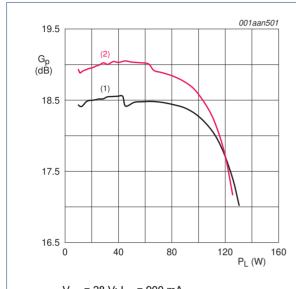


 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2400 MHz

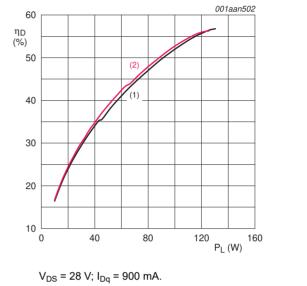
Fig 6. Single carrier IS-95 peak power as a function of load power; typical values

7.3 Pulsed CW



- V_{DS} = 28 V; I_{Dq} = 900 mA.
- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 7. Pulsed CW power gain as a function of load power; typical values

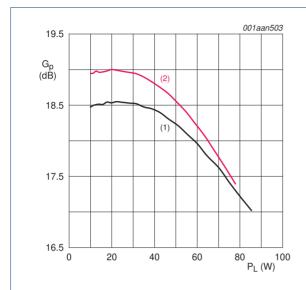


- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 8. Pulsed CW drain efficiency as a function of load power; typical values

7.4 Single carrier W-CDMA

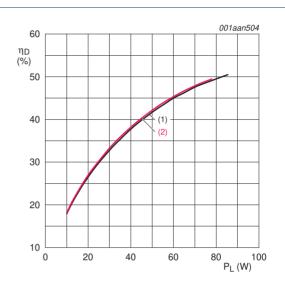
3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2400 MHz

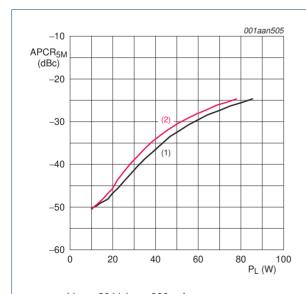
Fig 9. Single carrier W-CDMA power gain as a function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 900 mA.

- (1) f = 2300 MHz
- (2) f = 2400 MHz

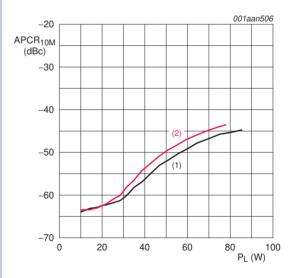
Fig 10. Single carrier W-CDMA drain efficiency as a function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 900 mA.

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 11. Single carrier W-CDMA ACPR at 5 MHz as a function of load power; typical values



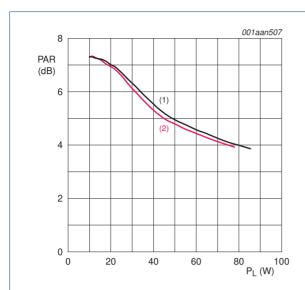
 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 12. Single carrier W-CDMA ACPR at 10 MHz as a function of load power; typical values

BLF7G24L-100; BLF7G24LS-100

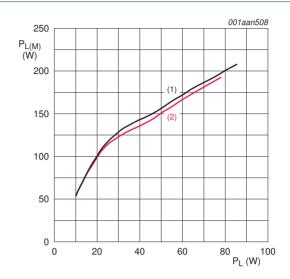
Power LDMOS transistor



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 13. Single carrier W-CDMA peak-to-average power ratio as a function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 900 \text{ mA}.$

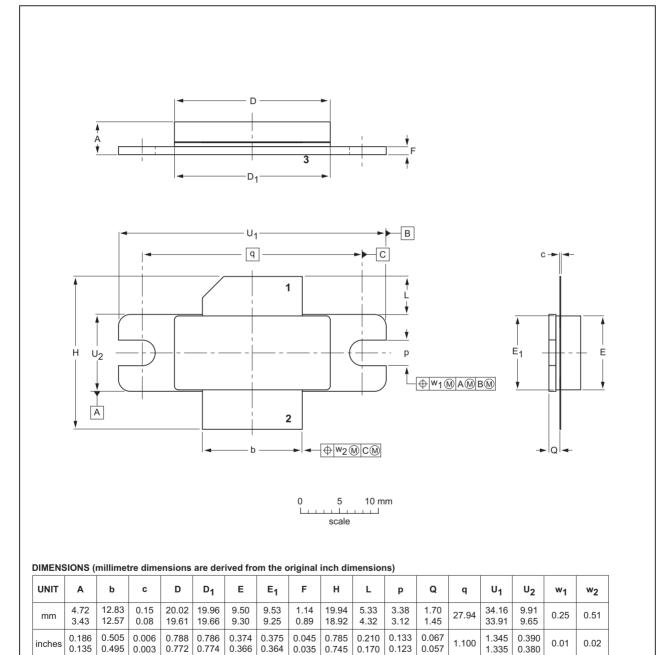
- (1) f = 2300 MHz
- (2) f = 2400 MHz

Fig 14. Single carrier W-CDMA peak output power as a function of load power; typical values

8. Package outline

Flanged ceramic package; 2 mounting holes; 2 leads

SOT502A



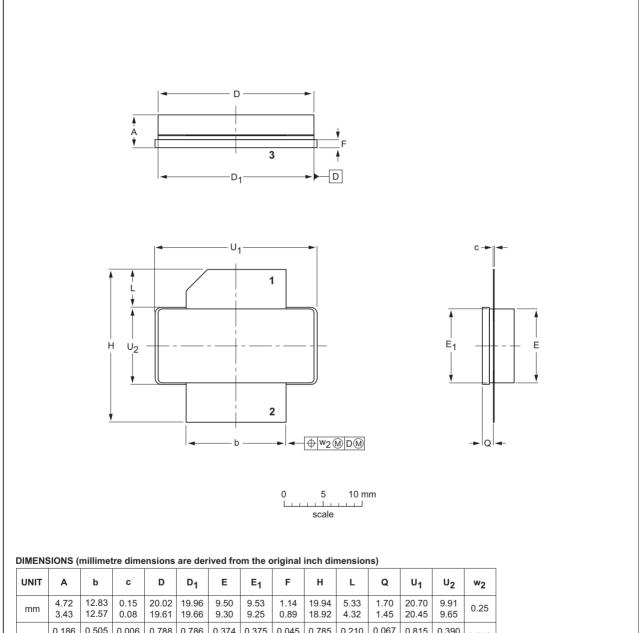
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT502A					-03-01-10- 12-05-02

Fig 15. Package outline SOT502A

9 of 14

Earless flanged ceramic package; 2 leads

SOT502B



												٠.	_	
mm	4.72	12.83	0.15	20.02	19.96	9.50	9.53	1.14	19.94	5.33	1.70	20.70	9.91	0.25
mm	3.43	12.57	0.08	19.61	19.66	9.30	9.25	0.89	18.92	4.32	1.45	20.45	9.65	0.23
inches	0.186												0.390	0.010
inches	0.135	0.495	0.003	0.772	0.774	0.366	0.364	0.035	0.745	0.170	0.057	0.805	0.380	0.010

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT502B					07-05-09 12-05-02

Fig 16. Package outline SOT502B

9. Abbreviations

Table 8. Abbreviations

TUDIO OI ADDI	- CVIACIONO
Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
IS-95	Interim Standard 95
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
N-CDMA	Narrowband Code Division Multiple Access
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

10. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
BLF7G24L-100_7G24LS-100 v.5	20150901	Product data sheet	-	BLF7G24L-100_7G24LS-100 v.4				
Modifications:	guidelines	he format of this document has been redesigned to comply with the new identity uidelines of Ampleon. egal texts have been adapted to the new company name where appropriate.						
BLF7G24L-100_7G24LS-100 v.4		Product data sheet	-	BLF7G24L-100_7G24LS-100 v.3				
BLF7G24L-100_7G24LS-100 v.3	20110405	Preliminary data sheet	-	BLF7G24L-100_7G24LS-100 v.2				
BLF7G24L-100_7G24LS-100 v.2	20100714	Objective data sheet	-	BLF7G24L-100_7G24LS-100 v.1				
BLF7G24L-100_7G24LS-100 v.1	20100414	Objective data sheet	-	-				

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BLF7G24L-100 7G24LS-100#5

BLF7G24L-100; BLF7G24LS-100

Power LDMOS transistor

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BLF7G24L-100; BLF7G24LS-100

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Power LDMOS transistor

13. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
2	Pinning information
3	Ordering information
4	Limiting values
5	Thermal characteristics
6	Characteristics 3
7	Test information
7.1	Ruggedness in class-AB operation 3
7.2	Single carrier IS-95
7.3	Pulsed CW
7.4	Single carrier W-CDMA
8	Package outline
9	Abbreviations11
10	Revision history
11	Legal information
11.1	Data sheet status
11.2	Definitions
11.3	Disclaimers
11.4	Trademarks13
12	Contact information
12	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.